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Structural Characteristic and Superconducting Performance of MgB_2 Fabricated by Mg Diffusion Process

Minoru Maeda¹, Jung Ho Kim² and Shi Xue Dou²

¹*Department of Physics, College of Science and Technology, Nihon University*

²*Institute for Superconducting and Electronic Materials,
Australian Institute of Innovative Materials, University of Wollongong*

¹*Japan*

²*Australia*

1. Introduction

The phenomenon of superconductivity, which arises from an unusual quantum mechanism below a superconducting critical transition temperature (T_c), shows unique physical properties, namely, exactly zero direct current (dc) electrical resistance, the Meissner effect associated with nearly perfect diamagnetism, and the Josephson effect in two weakly coupled superconductors which may have applicability in high-speed, high-sensitivity, low-voltage sensors and switches. Thanks to these valuable characteristics, today, superconducting materials are having a considerable influence on the development of the next generation of medical services, electrical power systems, transportation, communication technology, and integrated circuits. Thus, our energy-hungry world increasingly requires those technologies and superconductors are becoming indispensable materials.

Superconductivity was discovered by Heike Kamerlingh Onnes in 1911. It is one of the greatest discoveries in the history of science. After that, he tried to fabricate a superconducting magnet using lead (Pb), but it failed. From the failure of his experiment, he learned of the existence of the critical field of superconductors, which completely suppresses superconductivity. His dream was that a high magnetic field could be excited by magnets using superconductors, but it was left unfulfilled. In 1947, a compact helium liquefier was invented by Collins and coworkers, and it made possible some advance in theoretical and experimental studies related to superconducting magnets. From 1960 to 1990, niobium titanium (NbTi) and niobium tin (Nb_3Sn) superconductors were employed in many kinds of approaches towards technical development for real applications. These efforts formed the basis of technical application for magnets using metallic superconducting materials, and even now, many researchers are still making steady progress on it. As a result, superconducting materials have become widely applied in not only research magnets for laboratory use, but also various other instruments, which is more than what was expected. Specifically, magnetic resonance imaging (MRI)

equipment provides image contrast between different kinds of soft issues in the human body and it is essential to confirm the diagnosis of spinal disc herniation, anterior cruciate ligament injury, tumour, and stroke. Nuclear magnetic resonance (NMR) equipment is utilized on the cutting edge of genome-related research. In addition, superconducting magnetic energy storage (SMES), magnetic levitation systems for transportation, and large-scale magnets for confinement of plasma in fusion reactors are expected as the next generation of devices for energy production, its storage, and its distribution, even though they are still at the experimental stage of development. On the other hand, cooling technology, which is crucial for superconducting applications, has also maintained steady progress for the past 15 years. The most recent helium liquefier has smaller scale, longer operation life, and higher energy-saving compared with those a decade ago. Small, convenient cryocoolers without liquid helium have been put to practical use and developed into lower power consumption versions. A unique small pulse tube refrigerator without moving pistons in the low-temperature part of the device is also coming into actual utilization and can easily achieve a low temperature of 10 ~ 20 K. Thus, the development of cooling technology has given an impulse to superconducting applications.

Despite the recent progress of cooling technology, today, the majority of current practical superconducting devices are still made of NbTi and Nb₃Sn superconductors, which have the low T_c values below 20 K. MRI is one of the conventional superconducting devices and has been critical to our high-quality healthcare. However, only 10 % of human beings utilize the superconducting technology in the world. The most serious cause of disturbing its largely widespread use is to need liquid Helium for activating MRI magnets at 4.2 K. The cryogen is expensive and unmanageable, and its resource is exhaustible. In order to promote its widespread use and reduce operating cost, the next generation of superconducting technology must eliminate the use of liquid cryogen bath cooling and its real application has been strongly required. Currently, the most promising materials are thought to be bismuth strontium calcium copper oxide (BSCCO), yttrium barium copper oxide (YBCO), and magnesium diboride (MgB₂). MgB₂, a metallic compound, shows T_c of ~ 39 K, the highest value that has been reported for conventional metallic superconductors, and its superconductivity was discovered by Jun Akimitsu's group in 2001 (Nagamatsu et al., 2001). Owing to its large thermal margin than Nb based superconductors, MgB₂ superconducting materials have been judged potentially capable of meeting the needs of the next-generation superconducting applications operated at 15~30 K. MgB₂ materials also show superior characteristics for industrial applications including that (1) the manufacture method is much easier to that of NbTi wires, (2) the raw materials are much cheaper than that of YBCO thin films and BSCCO wires, and the manufacturing cost would potentially be lower than that of NbTi wires, (3) the density is one third of NbTi and it can yield triple length wire using the same mass of raw materials, (4) the charging rate of the magnet is faster than that of NbTi magnet, (5) the lower anisotropy and the larger coherence length do not make the weak link problem severe compared with YBCO thin films and BSCCO wires (Larbalestier et al., 2001). Although the T_c values of YBCO and BSCCO show 93 K and 110 K, respectively, and those are much higher than that of MgB₂, the prices of those conductors seem not to be reduced in spite of enormous efforts for more than 20 years. In these regards, therefore, MgB₂ materials have been energetically studied for industrial applications in the world since the discovery of the superconductivity.

2. MgB₂ material

2.1 Crystal and electrical structure

In 1954, the crystal structure of MgB₂ was first identified by an X-ray diffraction investigation using nickel-filtered Cu K α radiation (Jones & Marsh, 1954). MgB₂ possesses the simple AlB₂ type structure, and its corresponding space group, crystal system, and Laue-symmetry class are P6/mmm, hexagonal, and 6/mmm, respectively. The structure consists of alternating layers of close-packed ionized Mg²⁺ atoms, which are separated by honeycomb-type boron sheets. In the case of pure MgB₂ samples without external forcing such as hydrostatic pressure, the *a*-lattice parameter is estimated to range from ~ 3.083 to ~ 3.086 Å (Jones & Marsh, 1954; Jorgensen et al., 2001), with the variation most likely to be due to disorder in the honeycomb lattice. By contrast, the *c*-lattice parameter shows nearly the same value of ~ 3.521 Å. This may reflect the fact that in the case of close-packed hexagonal structure, the slip directions are essentially $[\bar{1}\bar{1}0]$, $[2\bar{1}0]$, and $[\bar{1}20]$ in the *ab* plane, while expansion and contraction along the *c*-axis direction hardly occurs. The fractional coordinates (*x*, *y*, *z*) for Mg and B atoms are allocated to the 1*a* site of (0, 0, 0) and the 2*d* site of (1/3, 2/3, 1/2). The site occupancies of Mg and B are observed to be ~ 0.95 -1.00 and 1.00, respectively (Mori et al., 2002; Tsirelson et al., 2003; Kazakov et al., 2005). The atomic displacement parameters *U* of Mg and B atoms are also observed to be ~ 0.0049 -0.0060 Å² and ~ 0.0042 -0.0080 Å², respectively (Mori et al., 2002; Tsirelson et al., 2003; Kazakov et al., 2005).

Band structure calculations on MgB₂ (An & Pickett 2001; Kortus et al., 2001) suggest that the bands at the Fermi level (*E_F*) mainly originate from the orbitals of boron due to substantially ionized Mg, and there are four conduction bands, namely, two σ bands delivered from the σ bonding $2s/2p_{x,y}$ orbitals and two π bands delivered from the π -bonding and the anti-bonding $2p_z$ orbitals. The former bands are hole types and occur in two-dimensional (2D) cylindrical forms. The latter bands are both hole type and electron type, and form three-dimensional (3D) tubular networks. The σ states are localized and confined in the boron layers, while the π states are delocalized in all directions. The σ bands within boron sheets are strongly covalent, whereas the π bands over the whole crystal show metallic behaviour, reflecting the lack of covalent bonding (Mazin & Antropov, 2003). The 2D strongly covalent states and the 3D metallic-type states mainly contribute to the total density of states (DOS) at the Fermi energy (*E_F*).

Calculations of both the band structure and the lattice dynamics for MgB₂ indicate that there are four distinct phonon modes at the Brillouin zone center (Γ), namely the A_{2u} , B_{1g} , E_{1u} and E_{2g} modes (Bohnen et al., 2001; Yildirim et al., 2001). The A_{2u} singly degenerate mode involves the vibration of Mg and B layers in opposite directions along the *c* axis. The B_{1g} singly degenerate mode is responsible for the vibrations of B atoms in opposite directions along the *c* axis, with the Mg atoms stationary. On the other hand, the others are doubly degenerate modes and involve only in-plane motions along the *x* or *y* axis. For the E_{1u} mode, the Mg and B layers move in opposite directions. The E_{2g} mode involves the vibration of the B ions in opposite directions, with the Mg ions stationary. The E_{2g} in-plane boron phonons show giant anharmonicity, are strongly coupled to the σ bands, and thus change the $2s/2p_{x,y}$ orbital overlap. The strong coupling between the holes of the σ bands and the E_{2g} mode is responsible for the high *T_c* in MgB₂. The π band charge carriers also become superconducting and

contribute to unusual superconducting behaviour in MgB_2 which is not observed in conventional superconductors. Since the two properties of the σ bands are very similar and those of the π bands are very similar, even though one π band is hole type and the other is electron type, the electronic structure is usually simplified to one σ band and one π band. Therefore, MgB_2 is known and described as a two-band superconductor (Liu et al., 2001).

2.2 Unique characteristic caused by two-band and two-gap structure

MgB_2 is known to be theoretically and experimentally identified as the first superconductor where two superconducting gaps clearly exist (Xi, 2008; Tajima, 2005). The unique two-band and two-gap structure has an influence on the resistivity behaviour in the normal state. In the year of discovery, it became well known that the residual resistivity ratio (RRR) was independent of T_c in polycrystalline MgB_2 samples. Specifically, many MgB_2 samples showed widely different RRR values despite having similar T_c values around ~ 39 K (Buzea & Yamashita, 2001). In the case of the high T_c , the disorder effects on it (Eisterer, 2007) due to poor crystallinity and lattice strain can be negligible, and thus, the RRR value calculated from the residual resistivity was thought to depend on impurity contamination in a sample. This indicates that lower RRR is caused by a larger amount of impurity phase, even though it should be noted that the residual resistivity is partially attributable to extrinsic effects such as lack of connectivity associated with cracks, voids, and low mass density (Rowell, J. M. 2003). In the case of the two-gap superconductivity model (Golubov & Mazin, 1997), non-magnetic impurities may contribute to pair breaking, which is similar to the effects of magnetic impurities in a conventional s -wave superconductor. Thus, it was difficult to theoretically understand the observed unclear correlation between the RRR and the T_c . Regarding this issue, Mazin et al. clearly explained the mechanism by pointing out the very weak impurity scattering between the σ and the π bands compared with the intraband impurity scattering between the $\sigma\sigma$ and $\pi\pi$ sub-bands, due to the particular electronic structure in MgB_2 (Mazin et al., 2002). It was also found that the $\pi\pi$ scattering rate is larger than the $\sigma\sigma$ scattering rate. In addition, they indicated that the T_c is given by the maximum eigenvalue of the superconducting coupling constant λ for the $\sigma\pi$ and the $\pi\sigma$ interband coupling, and the $\sigma\sigma$ and $\pi\pi$ intraband coupling, while the conductivity is the sum of all the conducting channels responsible for the interband and intraband couplings. The estimated λ for the $\sigma\sigma$ intraband coupling showed the highest value, suggesting that the T_c is affected by the σ band. These results provide the conclusion that because impurities have a stronger effect on the scattering rate of the π band in preference to the σ band, and thus the residual resistivity, they may not contribute to the interband scattering and T_c .

The upper critical field behaviour of MgB_2 was also found to be very different from that of a conventional phonon-mediated Bardeen, Cooper, and Schrieffer (BCS) superconductor with a single-band structure. A unique upward curvature of $B_{c2}(T)$ parallel to the ab plane near T_c was observed in single crystal MgB_2 samples (Zehetmayer et al., 2002; Lyard et al., 2002). This upward curvature can be well explained by using the Ginzburg-Landau theory, suggesting that the B_{c2} is determined by the Ginzburg-Landau parameter and the condensation energy (Eisterer, 2007). In the case of MgB_2 , which has the two-band structure, the total condensation energy depends on the sum of all the energies arising from the σ band, the π band, and the interaction between the two bands (Eisterer et al., 2005). These condensation energies in the temperature range from absolute zero to T_c show different

behaviour from each other. In particular, the contribution of the π band to the total condensation energy at 0 T in temperatures above 30 K rapidly increases, while that below 30 K is negligible. This is the reason why the $B_{c2}(T)$ of MgB₂ shows a positive curvature near T_c . The unique slope can make the zero-temperature $B_{c2}(0)$ significantly higher than that estimated from a single-gap dirty superconductor model (Gurevich, 2003). In addition, an interesting scenario relating to $B_{c2}(T)$ for dirty two-gap superconductors was pointed out by Gurevich (Gurevich, 2007). It is assumed that MgB₂ can be identified as a simple bilayer sample where two thin films corresponding to the σ and π bands are separated by a Josephson contact, which reflects the weak interband coupling in MgB₂. From the two-gap dirty-limit theory for the BCS matrix constants (Golubov et al., 2002), the temperature dependence of B_{c2} is mostly determined by whether the σ film or the π film is dirtier. Provided that the π film is much dirtier than the σ film, the global $B_{c2}(T)$ of the bilayer at higher temperature is mainly controlled by the σ film with the higher B_{c2} , while the π film takes over at lower temperatures. This leads to a considerable upturn in the global B_{c2} curve at low temperatures, which can not be estimated from a single-gap dirty-limit superconductor. This interesting scenario for B_{c2} at low temperatures delivered from the simple bilayer model is indirectly demonstrated by experimentally observed B_{c2} curves for alloyed MgB₂ thin films (Braccini et al., 2005). Specifically, an anomalous upward curvature of $B_{c2}(T)$ at low temperatures observed in a carbon-alloyed thin film provides a record high value of $B_{c2}(4.2\text{K}) = 51\text{ T}$ parallel to the *ab* plane. The extrapolation of the $B_{c2}(T)$ curve to $T = 0\text{ K}$ may reach over $\sim 60\text{ T}$, approaching the paramagnetic limit of 65 T which is calculated from the conventional BCS theory (Sarma, 1963). This value is significantly higher than those for NbTi and Nb₃Sn superconductors, which are widely used in superconducting applications now. Moreover, Gurevich pointed out that given the case of electron-phonon coupling, the paramagnetic limit of MgB₂ is estimated to be $\sim 130\text{ T}$ (Gurevich, 2007). This means that there is still large room for a further increase in B_{c2} from optimum dirty conditions of the intraband and the interband behaviour. Therefore, we can extract a conclusion that the two-gap superconductor MgB₂ is suitable for superconducting applications in higher operating temperatures and fields, which can not be reached via the use of Nb-based superconducting materials.

2.3 Current status in development for superconducting application

Two major critical issues facing MgB₂ polycrystalline materials such as wires and bulks for the next generation of superconducting applications are weak grain connectivity and lack of pinning centers (Rowell, J. M. 2003; Eisterer, 2007). In order to improve rapid J_c degradation caused by its weak pinning behaviour in pure MgB₂ wires and bulks, so far, many doping materials have been tested since the discovery of its superconductivity. The first successful dopant for this was silicon carbide (SiC) and its additive improved the irreversibility field (B_{irr}) and J_c (Dou et al., 2002). Numerous researchers focused on the impressive results and then started to do many studies related to carbon (C) containing dopants for real superconducting applications. Even now, SiC is still known to be one of the most effective dopants for MgB₂ materials. Specifically, B_{c2} values near 0 K for the SiC-doped MgB₂ wires fabricated by the *in situ* method (Sumption et al., 2005) and coated-conductors on SiC fibers prepared from hybrid physical-chemical vapor deposition (HPCVD) (Ferrando et al., 2005) were 33 T and 55 T, respectively. These values are much higher than those of NbTi and Nb₃Sn. Similar doping materials, nano-carbon (Soltanian et al., 2003), carbon nanotubes

(Yeoh et al., 2004), and boron carbide (Yamamoto et al., 2005a) were also found to effectively improve the in-field J_c in MgB_2 materials. Thus, it has been found that the carbon (C) element is indispensable for superconducting applications of MgB_2 .

From structural analysis of C-doped MgB_2 single crystals (Kazakov et al., 2005), the a -lattice parameter was observed to decrease drastically due to the C doping effect. The lattice shrinkage is most likely due to C substitution at B sites and to the difference in atomic radius between these two atoms, which may yield substitutional defects in the crystal lattice. This is because the C replacement effect accumulates in the B layer, and dislocations and its associated stacking faults may form when the accumulated strain exceeds the critical value. The existence of lattice defects in C-doped MgB_2 samples has been proven by experimental results (Kazakov et al., 2005; Avdeev et al., 2003; Zhu et al., 2007; Kim et al., 2012). Specifically, the considerable increase in the atomic displacement parameter at the Mg and B sites in C-doped single crystals reflects the enhancement of lattice disorder (Kazakov et al., 2005). The reason why reliability factors for Rietveld refinement in C-doped samples show high values compared with those for pure samples may be explained by the presence of local disorder in the lattice, which can not be described using conventional refined parameters (Kazakov et al., 2005; Avdeev et al., 2003). The C-doped thin films deposited by HPCVD, which shows a high B_{c2} at 0 K value of 70 T, are found to have intensive structural disorder caused by dislocations (Zhu et al., 2007a). In the case of SiC-doped tapes showing relatively low mass density compared with MgB_2 thin films, the MgB_2 grains are also found to show a large amount of interior contrast generated by intragrain defects that are likely due to lattice disorder (Zhu et al., 2007b). In addition, the relationship between lattice change and not only substitutional, but also interstitial defects in C-doped MgB_2 materials can be theoretically explained by Vienna *ab initio* calculations (Bengtson et al., 2010). Recently, boron vacancies were clearly observed in C-doped MgB_2 wires and it has been found that those vacancies generate intrinsic stacking faults within the MgB_2 grains, together with associated lattice distortion (Kim et al., 2012). Thus, in C-doped MgB_2 materials, the reduced unit cell volume caused by the lattice shrinkage leads to introduction of lattice disorder effects, which result in increasing scattering of charge carriers, reducing the mean free path, and thereby enhancing B_{c2} and J_c (Kazakov et al., 2005; Eisterer, 2007).

However, in the case of inorganic carbon compounds as C doping materials, due to its high melting points or its high decomposition temperature, high-temperature reaction is usually required to effectively cause the lattice shrinkage of the a -lattice parameter. These sintering conditions generally offer the disadvantage of grain growth associated with weak grain boundary pinning, because this pinning mechanism is also known to be effective in MgB_2 materials (Larbalestier et al., 2001; Eisterer, 2007). To address the problem, organic compounds as C doping materials with relatively low decomposition temperatures have been intensively studied from around 2006 (Kim et al., 2006; Hossain et al., 2009; Kim et al., 2010; Maeda et al., 2011a). One of the best known organic dopants that has been suggested to date is malic acid ($C_4H_6O_5$) (Kim et al., 2006). The advantage is that the carbohydrate melts and decomposes at a low temperature below the temperature of MgB_2 formation. The decomposition produces highly reactive and fresh C on the atomic scale for C substitution on B site in the lattice. Due to these excellent characteristics, the a -lattice parameter decreases even under low-temperature sintering conditions, and grain growth is suppressed, resulting in considerable enhancement of J_c and B_{c2} . Specifically, the J_c value at

4.2 K and 6 T for *in situ* processed C₄H₆O₅-doped MgB₂ wires exceeds 1.0×10^5 A/cm², which is comparable to that for commercial NbTi wires (Kim et al., 2010). The application of cold high pressure densification to those MgB₂ wires yielded a high J_c value of 4.0×10^4 A/cm² at 4.2 K and 10 T, which is the record value among conventional *in situ* powder-in-tube (PIT) processed MgB₂ wires (Hossain et al., 2009).

According to recent advanced microscopic analysis by using scanning transmission electron microscopy (STEM) and electron energy loss spectroscopy (EELS), un-reacted carbon agglomerates are found to be formed at grain boundaries in C-doped MgB₂ (Kim et al., 2012). The residual impurity arises from inhomogeneous mixing of starting materials including carbon compound as dopant and impedes supercurrent flow. In order to address the issue, recently, a carbon containing gas diffusion method by using oxygen-free pyrene (C₁₆H₁₀) was proposed (Maeda et al., 2011b). Pyrene is an aromatic hydrocarbon and its boiling temperature is 404 °C lower than the temperature of MgB₂ formation. Owing to the characteristic, molecular carbon delinked from pyrene gas homogeneously distributes into dense MgB₂ materials and it causes intensive structural disorder without any severe deterioration of grain connectivity. In addition, more recently, an alternative carbon doping method by using carbon encapsulated boron nanopowder made from a radio frequency plasma process was also proposed and the resultant C-doped MgB₂ wires showed high J_c performance due to very thin carbon layers on boron surface for its carbon homogenous distribution (Kim et al., 2011). Thus, the weak flux pinning problem has been well addressed by these recent advanced carbon doping methods, resulting in considerable improvement of high-field J_c of MgB₂.

On the other hand, the other major issue, the weak grain connectivity, has also known to be critical for the superconducting performance of MgB₂ since the discovery of its superconductivity (Rowell, J. M. 2003; Eisterer, 2007). This is more serious compared with the former major issue and it occurs in MgB₂ polycrystalline materials prepared from not only *in situ* reaction of Mg and B mixtures but also *ex situ* fabrication through the use of MgB₂ powder. The *in situ* PIT method is the most popular methods for fabricating MgB₂ conductors and the J_c performance is currently higher than that of *ex situ* processed conductors. However, the *in situ* processed conductors show numerous voids caused by MgB₂ formation (Kim et al., 2007). This is because the theoretical volume of the mixture ($V_{Mg} + V_{2B}$) is larger than the volume of the reacted MgB₂. The resultant mass density is limited to ~ 50 % of the theoretical density, and the porous structure significantly reduces the supercurrent-carrying area and the J_c for MgB₂ materials. In order to counter the severe problem, *in situ* Mg diffusion methods have been proposed (Canfield et al., 2001; Kang et al., 2001) and it seems to be the most effective method even though there is still room for real application.

2.4 Mg diffusion method

Mg diffusion into a B matrix for fabricating dense MgB₂ materials was suggested by Canfield et al. and Kang et al. around the same time (Canfield et al., 2001; Kang et al., 2001), soon after the discovery of superconductivity in MgB₂. Canfield et al. successfully fabricated the first MgB₂ wire using the Mg diffusion method (Canfield et al., 2001). The specific technique was to expose boron filaments to Mg vapour or liquid at 950 °C for 2 hours. The obtained conductor showed a very low residual resistivity of ~ 0.38 μΩcm and a high

density above 80 % of theoretical. Even now, MgB_2 conductors prepared by conventional *in situ* or *ex situ* PIT methods do not reach either value. On the other hand, Kang et al. first made high-quality MgB_2 thin films via a similar method (Kang et al., 2001). The successful technique was to deposit amorphous B thin films and sinter them in Mg vapor at 950 °C for 10-30 minutes. The self-field J_c at 5 K for the obtained film showed a high value of $\sim 6.0 \times 10^6$ A/cm² and a low residual resistivity of $\sim 2.0 \mu\Omega\text{cm}$, which was likely due to its highly dense structure. Thus, the Mg diffusion method was found to yield higher mass density of MgB_2 matrix in materials compared with conventional *in situ* PIT method, and it has been modified by many researchers for further enhancement of J_c and real applications of various materials such as wires and bulks since it was first discovered (Giunchi, 2003; Ueda et al., 2005; Togano et al., 2009).

For the synthesis of dense MgB_2 bulks, the reactive liquid Mg infiltration (RLI) technique was proposed by Giunchi (Giunchi, 2003). The method has the advantage that desired forms can be fabricated on a large scale and in an inexpensive way without hot pressing methods. The following is a brief procedure of the fabrication method. First, compacted B powders in contact with an appropriate amount of Mg bulk pieces are inserted into steel containers with desirable shapes. The containers are arc-welded in Ar atmosphere using a high-temperature resistant technique and then sintered at 750-950 °C. After sintering, the MgB_2 bulks are obtained by removal of the containers. The mass density of the obtained samples is ~ 2.40 g/cm³, and the transport J_c values at 4.2 K and 10 T reach 3.0×10^3 A/cm². Moreover, the RLI technique in combination with *in situ* PIT methods can be applied to the fabrication of monofilament and multifilament MgB_2 hollow wires (Giunchi et al., 2003). It is found that hollow cores are formed in the sintered wire due to Mg diffusion into the B matrix. The formed MgB_2 core was observed to have highly dense structure from SEM observation.

In order to address the problem of the low J_c at self field in MgB_2 bulks, the powder-in-closed-tube (PICT)-diffusion method was suggested by Ueda et al. (Ueda et al., 2005). The bulks were prepared by the following procedure. The starting Mg and B powders in appropriate amounts were separately packed into a stainless steel tube. The tube was deformed into a tape-shaped sample and both ends were sealed by bending and pressing. The samples were vacuum-sealed in a silicon dioxide (SiO_2) tube and then sintered at 800-900 °C. The obtained sample sintered at 800 °C for 60 hours exhibits well-connected small grains with sizes of 30-100 nm. The mass density is above 95 % of the theoretical density, and the self-field J_c value at 20 K reaches $\sim 8.6 \times 10^5$ A/cm² due to its good connectivity.

To achieve much less MgO secondary phase, as well as highly dense structure in MgB_2 conductors, an interface diffusion process was proposed by Togano et al. (Togano et al., 2006). The conductors were fabricated from an interface diffusive reaction between an Fe-Mg alloy substrate and B at 950 °C for 12 hours. The formed MgB_2 layer was observed to be composed of densely packed equi-axial grains of submicron size and without oxygen contamination. This group also suggested an internal Mg diffusion (IMD) process for further enhancement of J_c in MgB_2 wires (Hur et al., 2008). Specifically, 19-filament dense MgB_2 wires are fabricated by the internal Mg diffusion (IMD) process and the transport J_c values at 4.2 K and 10 T reach $\sim 1.0 \times 10^5$ A/cm² (Togano et al., 2009). This performance is the best J_c reported so far in MgB_2 wires. However, despite these attractive performances of Mg diffusion processed materials, very little work has been done on the effects of sintering temperature on the phase composition, lattice parameters, mass density, grain size, T_c , B_{c2} ,

and J_c in MgB_2 prepared from Mg diffusion process. In this study, therefore, we have systematically evaluated structural and superconducting properties in Mg diffusion processed MgB_2 bulks sintered under various heat-treated conditions.

3. Experimental

3.1 Sample preparation via Mg diffusion and evaporation processes

All samples were fabricated via Mg diffusion and evaporation processes, as shown in Fig. 1.

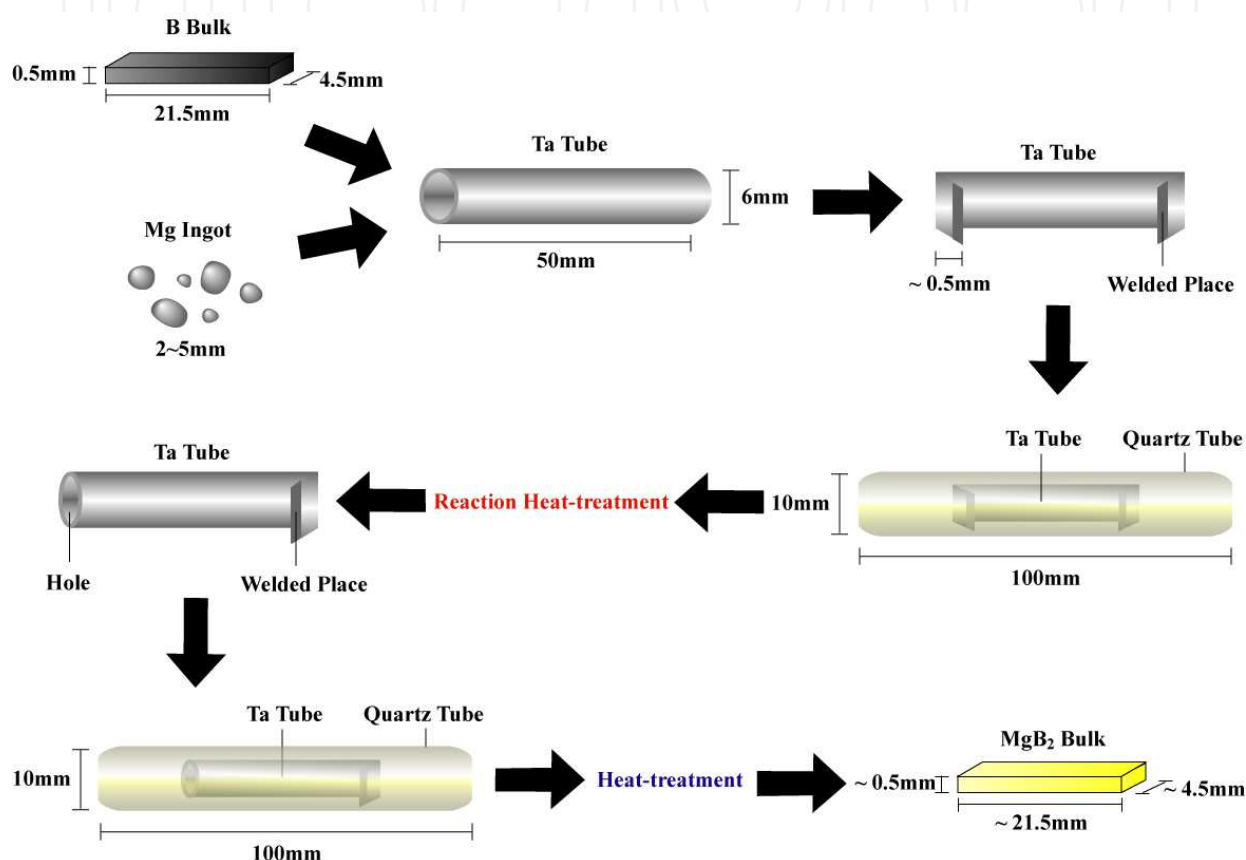


Fig. 1. Schematic diagram showing a fabrication method of MgB_2 via Mg diffusion and evaporation processes.

Mg ingots (purity 99.99 %, size 2-5 mm) and amorphous B powder (purity 99.995 %, size $0.25\ \mu\text{m}$) were used as starting materials and the molar ratio was chosen to be 1 : 1. The reason for using the large amount of Mg ingots is to eliminate Mg loss caused by MgO formation and to more homogeneously diffuse Mg into B matrix in comparison with what occurs in a Mg diffusion process with the stoichiometric molar ratio. Amorphous B powder was pressed into slabs with dimensions of $4.5 \times 21.5 \times 0.5\ \text{mm}$ under a pressure of 100 MPa. The compacted B powder and Mg ingots were placed in a Ta tube. Both ends of the Ta tube were sealed by a metal inert gas (MIG) welding method in a glove box filled with high purity Ar gas. During the MIG welding process, the Ta tube was heat-sunk with ice-cooled copper block to avoid heating the slab and Mg ingots. The sealed Ta tube was vacuum-sealed in a quartz tube and then heat-treated under four major types of sintering conditions that are (1) an one-step sintering process at $1100\ ^\circ\text{C}$ which is higher than the boiling point of

Mg, (2) an one-step sintering process at 660 °C which is higher than the melting point of Mg, (3) a two-step process sintered at 1100 °C for a short period of 6 minutes followed by second sintering at 660 °C, and (4) a two-step process sintered at 660 °C for 12 hours followed by second sintering at 1100 °C. After each sintering process for MgB₂ formation, a large amount of unreacted Mg remains in the sealed Ta tubes. In order to remove the residual Mg from MgB₂ sample, the Ta tube was pierced through and again vacuum-sealed in a quartz tube to undergo an Mg evaporation process at 680 °C for 0.5 hour.

3.2 Sample characterization

The phase composition was investigated from X-ray powder diffraction (XRD) patterns which were collected with a Rigaku RINT 2000 diffractometer using CuK α radiation. Rietveld refinement of the crystal structure was carried out with the RIETAN-2000 program (Izumi & Ikeda, 2000) and the structural parameters were refined by fitting the observed XRD patterns. The morphology and grain size were examined using a HITACHI S-4500 Scanning Electron Microscopy (SEM). The real and the imaginary component curves of ac susceptibility and the dc magnetization loops were evaluated by using a SQUID magnetometer (MPMS-5T, Quantum Design). The T_c and B_{c2} were determined by ac susceptibility measurements at $f = 76.97$ Hz with $\mu_0 H_{ac} = 10$ μ T and $\mu_0 H_{dc} = 0, 0.2, 0.5, 1, 2, 3, 4,$ and 5 T. The J_c values were derived from the magnetization hysteresis loops using the Bean critical state model (Chen & Goldfarb, 1989).

4. Results and discussion

4.1 Morphology and density

Figure 2 shows the SEM images of the surface of Mg diffusion processed samples via various sintering conditions. For reference, compacted amorphous B powder was also observed, as can be seen in Fig. 2(j). It was found that the one-step sintering process at 1100 °C yields well-developed crystalline grains, as shown in Fig. 2(a), (b), and (c). The crystal grains were also found to grow rapidly with an increase in sintering time. Specifically, the average grain sizes of samples sintered at 1100 °C for 0.5, 1, and 3 hours were observed to be approximately 0.8, 1.5, and 3.0 μ m, respectively. The mass densities of the corresponding samples are 2.2, 2.4, and 1.9 g/cm³, respectively, and close to the theoretical density of MgB₂. However, the drastic decrease in mass density from 2.4 g/cm³ to 1.9 g/cm³ is most likely due to the observed rapid growth caused by the increase in sintering time. It is well known that grain boundaries can act as pinning sites in MgB₂ materials (Larbalestier et al., 2001; Eisterer, 2007). The considerably large grains offer the disadvantage of lowering in-field J_c , even though high mass density is easily achieved by the one-step process at 1100 °C for the short sintering time. Contrary to the grain growth, the one-step sintering process at 660 °C for long sintering time ranging from 24 hours to 96 hours was found to leave grain size more or less the same, as can be seen in Fig. 2(d), (e), and (f). It is important to note that the average grain size is much smaller than that of Mg diffusion processed samples at 1100 °C and the grain shape shows poorly crystallized form. It is also well known that crystallinity associated with structural disorder in the lattice as well as grain boundaries can enhance the flux pinning effect (Yamamoto et al., 2005b; Eisterer, 2007). The low-temperature sintering process is advantageous in terms of both poor crystallinity and small grains.

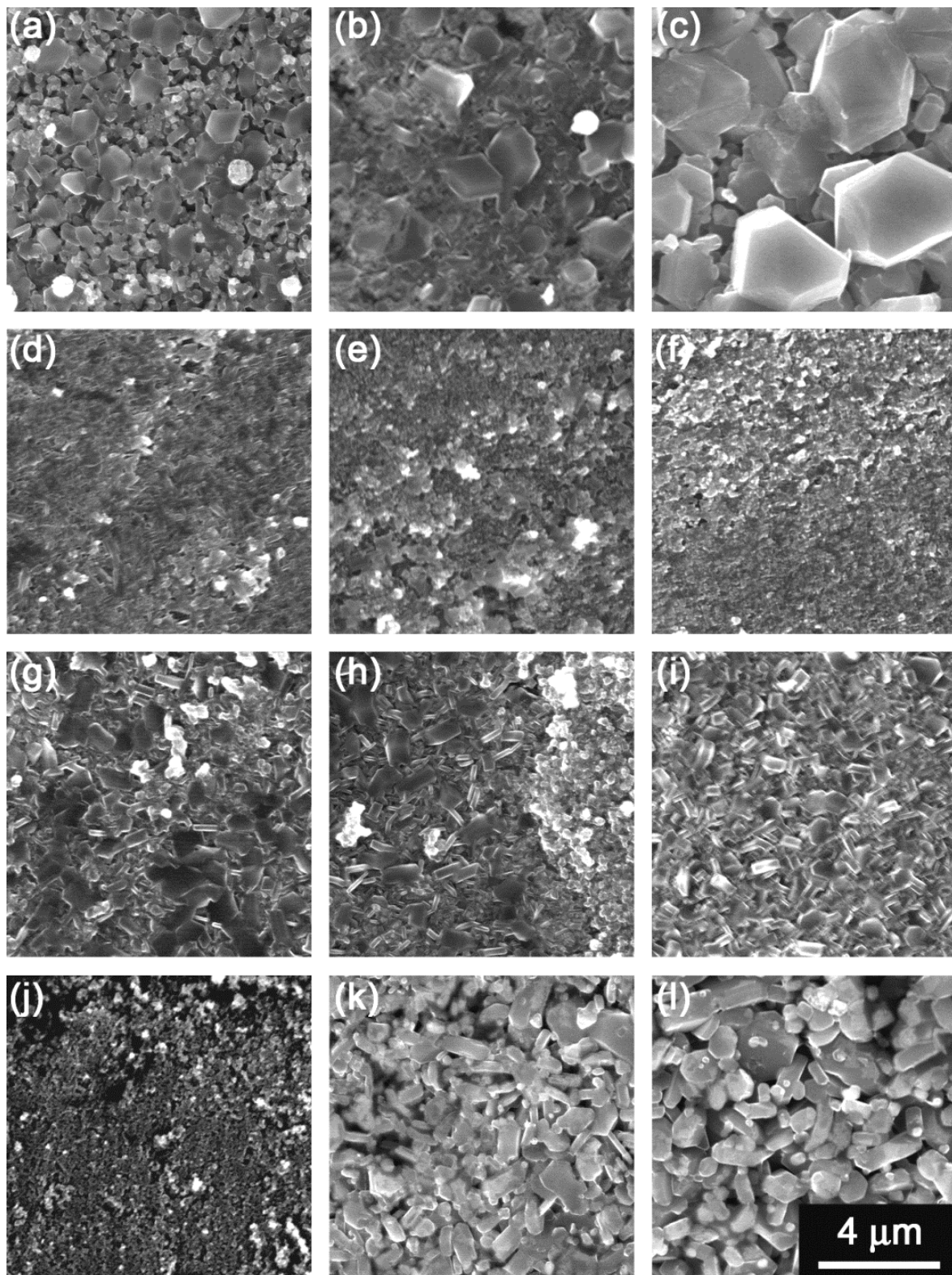


Fig. 2. Microstructure of Mg diffusion processed samples via various sintering conditions including (a) 1100 °C 0.5 h, (b) 1100 °C 1 h, (c) 1100 °C 3 h, (d) 660 °C 24 h, (e) 660 °C 48 h, (f) 660 °C 96 h, (g) 1100 °C 0.1h - 660 °C 3 h, (h) 1100 °C 0.1 h - 660 °C 6 h, (i) 1100 °C 0.1h - 660 °C 12 h, (k) 660 °C 12 h - 1100 °C 0.25 h, and (l) 660 °C 12 h - 1100 °C 0.5 h. (j) Microstructure of compacted B powder before sintering.

However, the Mg diffusion processed samples at 660 °C were brittle and the mass densities are ~ 1.5 g/cm³. The value is almost half of the theoretical density, even though the SEM images of the corresponding samples seem to be dense. The porous structure caused by the low density may intensively limit grain connectivity and hence supercurrent flow. On the other hand, the two-step process first sintered at 1100 °C for 0.1 hour followed by second sintering at 660 °C for 3 -12 hours was found to form well-developed crystalline grains, as can be seen in Fig. 2(g), (h), and (i). The average grain size is below 1 μ m and smaller than that of Mg diffusion processed samples via the one-step sintering at 1100 °C. However, unlike Mg diffusion processed samples via the one-step sintering at 660 °C which have small grains, the mass densities are ~ 2.4 -2.5 g/cm³ and those are above 90 % of the theoretical density. The two-step sintering process achieves both high density and small grains, which arise from the natures of high-temperature sintering and low-temperature sintering, respectively. In contrast to the highly dense structure related to the well-connected small grains, the two-step process first sintered at 660 °C for 12 hours followed by second sintering at 1100 °C for 0.25 - 0.5 hour was found to result in loosely connected grains, as can be seen in Fig. 2(k) and (l). The mass densities are ~ 1.7 g/cm³ and this result also confirm its porous structure. The corresponding samples were observed to have well-developed crystalline and relatively large grains. The two-step sintering process yields low-density structure and large crystal grains due to low-temperature sintering and high-temperature sintering, respectively.

4.2 Phase composition and lattice structure

All Mg diffusion processed samples were observed to have the same phase composition, which consists of MgB₂ with a trace amount of MgO from XRD θ -2 θ scans. Hereafter the samples will be referred as MgB₂ samples. In order to examine deeper insight of microstructure, structural parameters of four MgB₂ samples sintered via four major conditions were refined and its result is listed in Table 1. It was found that the *a*-lattice parameter is slightly changed owing to various sintering effects, while leaving the *c*-lattice parameter the same. The *a*-lattice parameter of the MgB₂ sample sintered at 660 °C for 48 hours shows 3.0850 Å, and it is the lowest value of the four samples. The decrease in the *a*-lattice parameter reduces the unit cell volume of MgB₂. The reduction may introduce structural disorder in the lattice and decrease the DOS at the *E_F* responsible for a considerable change in *T_c* and thus *B_{c2}*. The XRD full width at half maximum (FWHM) is well known to be closely related to crystallite size and structural disorder and it is also listed in Table 1. The one-step sintering process at 1100 °C and the two-step process first sintered at 660 °C followed by second sintering at 1100 °C were found to obtain relatively narrow FWHM reflecting well-crystallized and large grain. This is consistent with the SEM result, as can be seen in Fig. 2. On the other hand, the FWHM values of the rest of MgB₂ samples were observed to be much broader than those of the other MgB₂ samples. The broad FWHM of the MgB₂ sample sintered at the one-step process at 660 °C is caused by poorly crystallized and small grains, as also indicated by the SEM observation. However, it should be noted that the FWHM of the MgB₂ sample first sintered at 1100 °C followed by second sintering at 660 °C is comparable to that of the sample sintered at 660 °C for 48 hours, although the corresponding sample seems to have well crystallized grains which are distinctly larger than that of MgB₂ samples sintered at the one-step process at 660 °C. This indicates that thanks to the second sintering at the low temperature, the two-step process could achieve both a high

level of disorder and small grains in the high-density MgB₂ samples, which are essential for enhancing the flux pinning effect. The MgO nanoparticles are also well known to act as pinning sites in MgB₂ thin films (Eom et al., 2001; Singh et al., 2008), whereas it is difficult to control the size in polycrystalline MgB₂ samples and large MgO grains could impede supercurrent flow (Maeda et al., 2011a). In this respect, it is necessary to eliminate the MgO impurity from polycrystalline MgB₂ materials. However, the MgO secondary phase of the four MgB₂ samples is not sensitive to sintering conditions. This indicates that even Mg diffusion process could not avoid MgO formation.

Sintering condition	1100°C1h	660°C48h	1100°C0.1h - 660°C6h	660°C12h - 1100°C0.5h
X-ray powder diffraction data				
Radiation source	CuKα			
λ (Å)	1.54060 (CuKα ₁), 1.54443 (CuKα ₂)			
Δ2θ (°)	0.01			
Temperature (K)	298			
Goodness of fit				
s	1.32	1.27	1.23	1.23
Lattice parameters				
a (Å)	3.0864 (2)	3.0850 (2)	3.0859 (2)	3.0868 (2)
c (Å)	3.5210 (1)	3.5210 (1)	3.5210 (1)	3.5211 (2)
Unit cell volume				
V (Å ³)	29.047 (2)	29.020 (3)	29.038 (3)	29.054 (3)
Reflection of MgB ₂ (101)				
FWHM(°)	0.15	0.31	0.29	0.10
Weight fraction				
MgB ₂ (wt%)	95.9	95.8	96.3	96.1
MgO (wt%)	4.1	4.2	3.7	3.9

Table 1. Results of Rietveld refinement on XRD data for Mg diffusion processed samples via four major sintering conditions that are 1100 °C for 1 hour, 660 °C for 48 hours, 1100 °C for 0.1 hour followed by second sintering at 660 °C for 6 hours, and 660 °C for 12 hours followed by second sintering at 1100 °C for 0.5 hour. The fitting quality between the observed pattern and the calculated one was evaluated by goodness of fit *s*.

4.3 Influence on *T_c*

Figure 3 shows the real and imaginary components of the ac susceptibility for four MgB₂ samples sintered via four major conditions. It was found that the onset of diamagnetism at the dc field of 0 T for the MgB₂ sample sintered at 660 °C for 48 hours is ~ 38 K and 1 K lower than those for the other samples. The decrease in *T_c* is most likely due to lattice disorder caused by the reduction of unit cell volume, as indicated by the refinement result listed in Table 1. It is noteworthy that although the other three samples show ~ 39 K of the onset diamagnetism at the dc field of 0 T, the superconducting transition curves are different. Specifically, the transition width of the MgB₂ sample first sintered at 1100 °C followed by second sintering at 660 °C is ~ 1.5 K and approximately two times broader than that of the MgB₂ sample sintered by the one-step process at either 1100 °C or 660 °C. It was

reported that the broad transition width arises from the nature of two kinds of superconducting MgB_2 phases, which are good ordering phase and a relatively lower level of ordering phase owing to the two-step sintering process (Maeda et al., 2008). The lower level of ordering phase could be a cause for the broad FWHM responsible for structural disorder, as observed in the XRD pattern (Table 1). Contrary to this, the transition width of the MgB_2 sample first sintered at 660 °C followed by second sintering at 1100 °C is ~ 0.3 K, suggesting that the sample consists of nearly perfect crystallite MgB_2 grains without any lattice disorder.

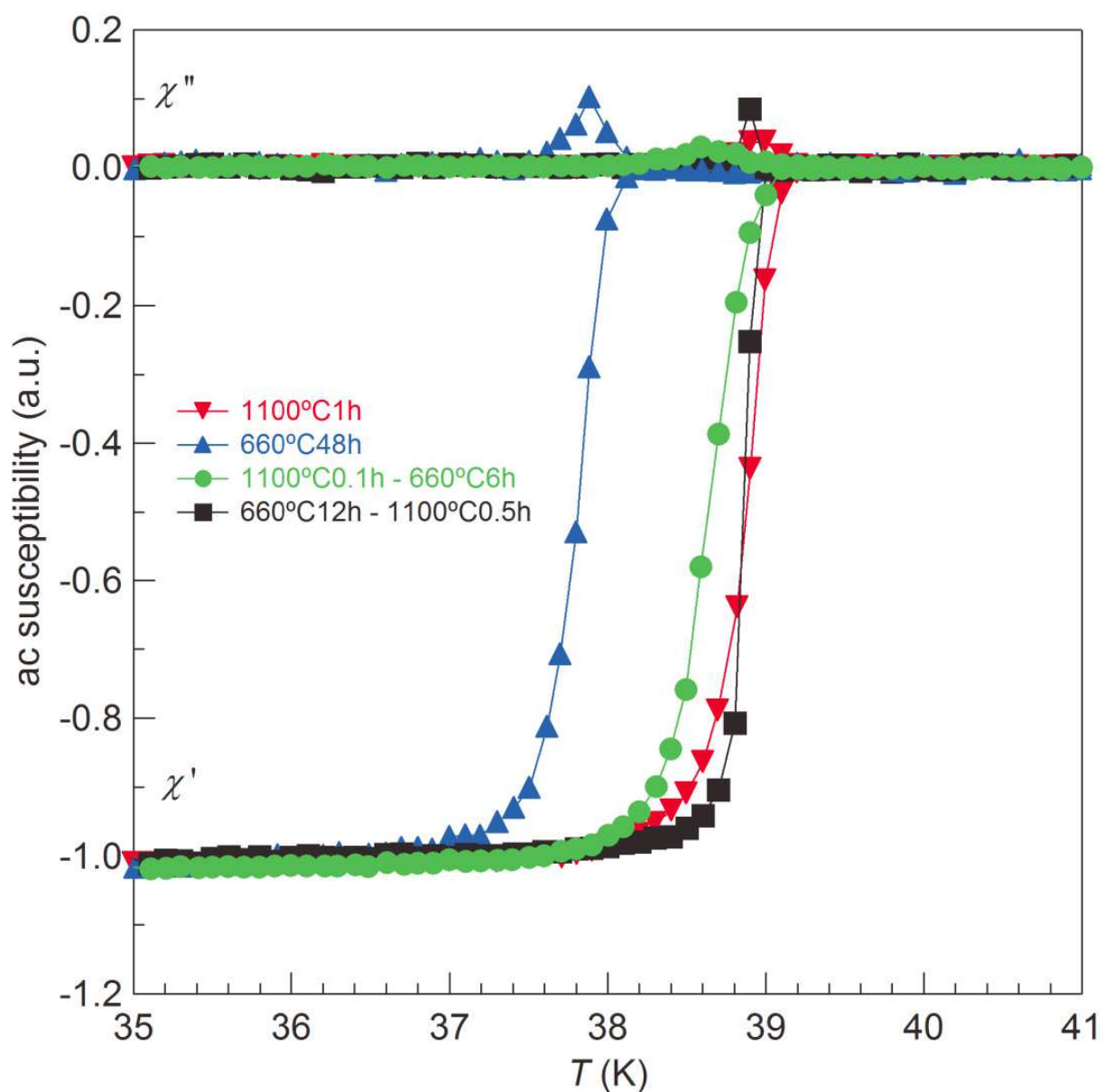


Fig. 3. The real and imaginary components of ac susceptibility with $f = 76.97$ Hz, $\mu_0 H_{ac} = 10$ μT , and $\mu_0 H_{dc} = 0$ T for Mg diffusion processed samples via four major sintering conditions that are 1100 °C for 1 hour, 660 °C for 48 hours, 1100 °C for 0.1 hour followed by second sintering at 660 °C for 6 hours, and 660 °C for 12 hours followed by second sintering at 1100 °C for 0.5 hour.

4.4 Influence on B_{c2}

Figure 4 shows the temperature dependence of B_{c2} for MgB₂ samples sintered via various conditions.

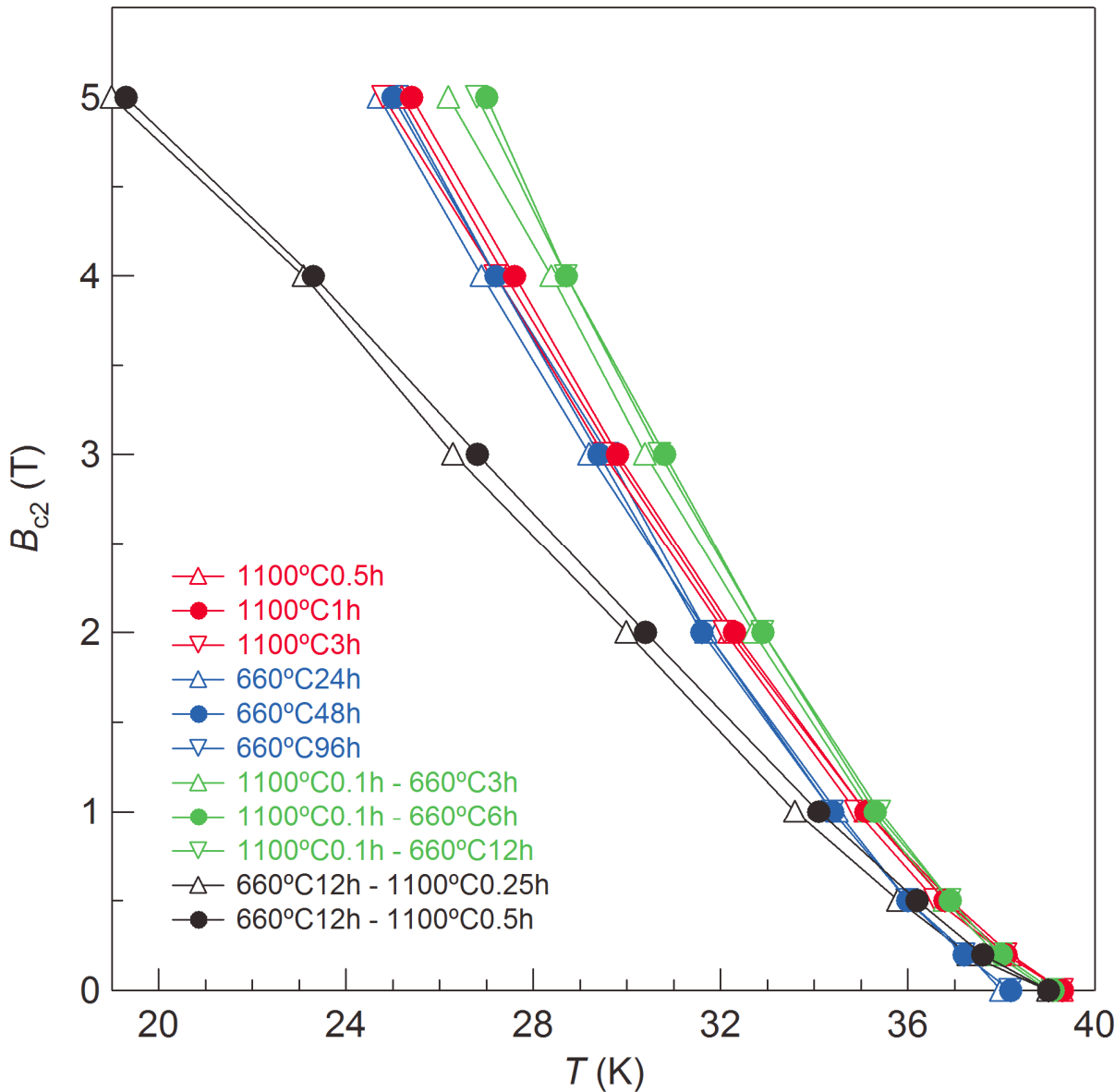


Fig. 4. The temperature dependence of B_{c2} derived from ac susceptibility with $f = 76.97$ Hz, $\mu_0 H_{ac} = 10 \mu\text{T}$, and $\mu_0 H_{dc} = 0, 0.2, 0.5, 1, 2, 3, 4$, and 5 T for MgB₂ samples sintered via various conditions.

It was found that although all MgB₂ samples has positive curvatures of B_{c2} at $T \sim T_c$ reflecting suppression of the diffusivity in the σ bands compared to that in the π bands (Gurevich, 2003), the behaviours of curves at lower temperature are considerably different. The B_{c2} slopes of the MgB₂ samples first sintered at 1100°C followed by second sintering at 660°C or sintered only at 660°C are steeper in comparison with those of the MgB₂ samples sintered at 1100°C . The structural disorder of both samples may be responsible for this. By contrast, the B_{c2} slopes of the MgB₂ samples sintered at 660°C followed by second sintering

at 1100 °C are intensively shelving compared to those of the other MgB₂ samples. This indicates that the MgB₂ samples do not have any lattice defects, as suggested by the result of the narrow superconducting transition (Figure 3).

4.5 Influence on J_c

Figure 5 shows the magnetic field dependence of J_c at 20 K for MgB₂ samples sintered via various conditions. It was found that the J_c curves are highly sensitive to sintering conditions which lead to considerably differences in MgB₂ structure, as shown in the results of SEM observation, XRD analysis, and ac susceptibility. The most noticeable feature shown in this figure is that the in-field J_c of the MgB₂ samples sintered at 1100 °C followed by

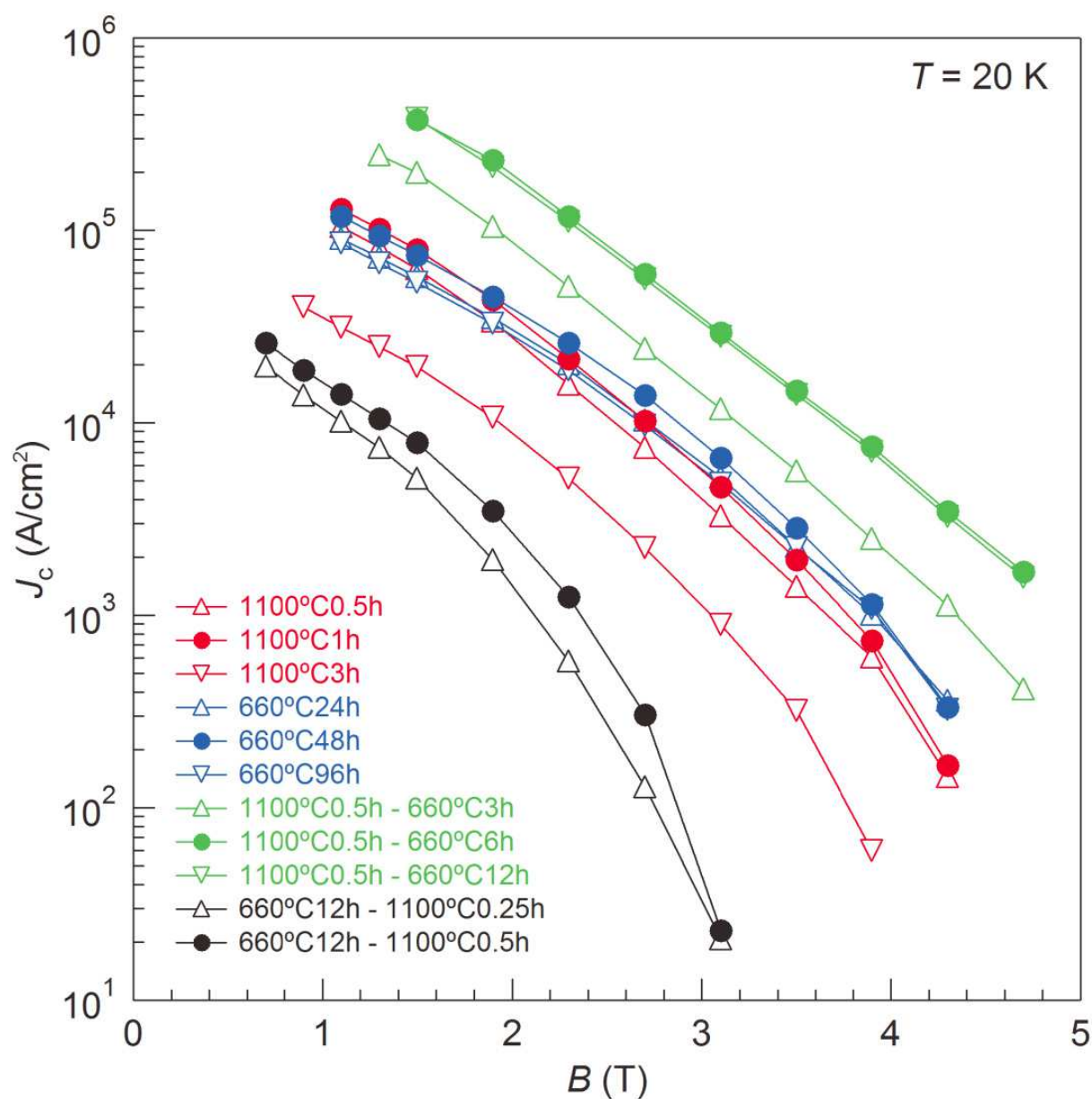


Fig. 5. Magnetic field dependence of J_c at 20 K for MgB₂ samples sintered via various conditions.

second sintering at 660 °C is significantly higher than those of the other MgB₂ samples. The enhancement of J_c at not only low field but also high field is clearly due to the two-step sintering process which yields well-connected small grains with a high level of disorder in highly dense MgB₂ samples. It is also interesting to note that even though the J_c of the MgB₂ sample sintered at 1100 °C for 1 hour is nearly the same as that of the MgB₂ sample sintered at 660 °C for 48 hours, the behaviours of the curves are somewhat different. Specifically, the low-field J_c of the MgB₂ sample sintered at 1100 °C for 1 hour is slightly higher than that of the MgB₂ sample sintered at 660 °C for 48 hours, whereas the corresponding behaviours of high-field J_c are distinctly opposite. This results from high density and lack of pinning sites caused by good crystallinity, which are responsible for the increase in self-field J_c and the decrease in high-field J_c , respectively. Owing to the low density and nearly perfect crystallization, the MgB₂ samples sintered at 660 °C followed by second sintering at 1100 °C show the lowest values of in-field J_c in all MgB₂ samples.

5. Conclusion

In summary, this chapter has introduced structural characteristic and superconducting performance of pure MgB₂ polycrystalline samples fabricated by Mg diffusion processes. The Mg diffusion processes easily yield MgB₂ phase and a trace amount of MgO phase in polycrystalline samples. The microstructure and mass density of the MgB₂ samples can be controlled by Mg diffusion processes via various sintering conditions. The two-step sintering process, namely, the sintering for a short period of 0.1 hour at 1100 °C first, followed by the second sintering at 660 °C, produces highly dense MgB₂ samples characterized by well-connected small grains with a high level of disorder. The unique feature results in considerable improvement of B_{c2} and in-field J_c . Therefore, Mg diffusion process is critical for controlling the structure of MgB₂ polycrystalline samples, and there is great potential for further enhancement of J_c by careful optimisation of sintering conditions.

6. References

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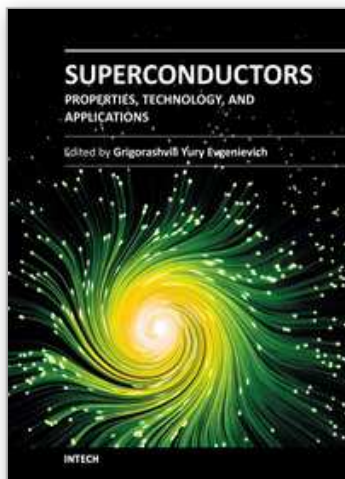
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Book "Superconductors - Properties, Technology, and Applications" gives an overview of major problems encountered in this field of study. Most of the material presented in this book is the result of authors' own research that has been carried out over a long period of time. A number of chapters thoroughly describe the fundamental electrical and structural properties of the superconductors as well as the methods researching those properties. The sourcebook comprehensively covers the advanced techniques and concepts of superconductivity. It's intended for a wide range of readers.

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University Campus STeP Ri
Slavka Krautzeka 83/A
51000 Rijeka, Croatia
Phone: +385 (51) 770 447
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InTech China

Unit 405, Office Block, Hotel Equatorial Shanghai
No.65, Yan An Road (West), Shanghai, 200040, China
中国上海市延安西路65号上海国际贵都大饭店办公楼405单元
Phone: +86-21-62489820
Fax: +86-21-62489821

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